#### PATENT APPLICATION

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q78724

Takaaki CHOSOKABE, et al.

Appln. No.: 10/724,253

Group Art Unit: 1751

Confirmation No.: 1604

Examiner: Kallambella M. Vijayakumar

Filed: December 1, 2003

For: SIN

SINTERED BODY FOR THERMISTOR DEVICES, THERMISTOR DEVICE AND

TEMPERATURE SENSOR

### **DECLARATION UNDER 37 C.F.R. § 1.132**

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

I, Takaaki CHOSOKABE, declare and state as follows:

I graduated from Nagoya Institute of technology in March of 1993, receiving a Bachelor's Degree in the Department of Material Engineering. Since April of 1993 to the present, I have been employed by NGK SPARK PLUG CO., LTD., where I have been engaged in the research and development of temperature sensors.

I am co-inventor of the invention described and claimed in the above-identified application.

I am familiar with the Office Action dated November 2, 2006, where claims 1-4 and 8 were rejected as being anticipated by U.S. Patent No. 5,403,461 to Tuller.

First, I explain why I believe my invention defines novel subject matter. Secondly, I report below on comparative experimentation that was conducted by myself or under my direct supervision. The test results demonstrate that the presence of a transition metal other

than Mn and the at least one element selected from elements of Group 3 in the Periodic Table adversely affects the temperature detection performance of the thermistor device over a wide temperature range from a low temperature of around 100°C to a high temperature range of 900°C. Tuller et al., which discloses incorporating transition elements other Mn and the at least one element selected from elements of Group 3 in the Periodic Table, such as Cr, Fe, Co, Ni, Cu, Ti, Zr and Hf, did not recognize this characteristic feature of my invention. For these reasons, not only does my invention define novel subject matter, it is also patentable over Tuller et al.

### 1. Novelty with Respect to Tuller et al.:

Tuller et al. at column 5 broadly characterizes the solid solution as being represented by the Formula  $(A_{1-j}D_j)_x(B_{1-k}E_k)_yO_zX_w$ . My claims exclude La, yet this is expressly allowed by the broad formula of Tuller et al. Likewise, my claims <u>exclude</u> any transition metal other than Mn and the at least one element selected from Group 3, yet the broad formula of Tuller et al. allows for the presence of a plurality of transition elements such as Cr, Fe, Co, Ni, Cu, Ti, Zr and Hf <u>in addition to Mn.</u> Moreover, there is nothing in Tuller et al. which would lead one of ordinary skill to select the narrow range of compositions covered by my claims. I understand that under U.S. practice, a broadly overlapping formula of the prior art is not novelty destroying where the prior art also does not lead one skilled in the art to arrive at the claimed subject matter. In my opinion, this is surely the case here. If the Examiner were correct, then no one could obtain a new patent on a thermistor device because Tuller et al.'s broad disclosure at column 5 covers nearly all potential compositions for use in making a sintered body for a thermistor device.

On the other hand, if Tuller et al. did direct one skilled in the art to exclude La, which they do not, and if Tuller et al. did direct one skilled in the art to exclude transition metals other than Mn and the at least one element selected from elements of Group 3 in the Periodic Table, which they also do not, then the Examiner's position would be understandable. However, that is not the case, and for at least these reasons, the sintered body for thermistor devices as claimed in my application defines novel subject matter.

#### 2. Comparative Experimentation:

Sintered bodies were prepared including a Group 3 element selected from Y, Sm, Nd and Gd; a Group 2 element selected from Ca and Sr; Mn and Al in the indicated amounts; and one of Fe and Ni (i.e., a transition metal other than Mn and the at least one element selected from elements of Group 3 excluding La). The samples thus prepared were evaluated with respect to initial electrical resistance at 100°C and 900°C, electrical resistance after heating at 100°C and 900°C and the change in electrical resistance in terms of temperature (°C) as described at pages 25-27 of my specification, the results of which are set forth in the Table below. Particularly, the change in electrical resistance in terms of temperature is calculated in accordance with Formula (3) at page 26 of my specification. A smaller value represents a smaller change in resistance to a heat profile and is therefore advantageous in promoting high temperature detection accuracy.

Comparative Example 7 of composition (YCa)(MnAl**Fe**) having a change in electrical resistance in terms of temperature (°C) of 13 and 15 at 100°C and 900°C, respectively, is directly comparable to Inventive Examples 1 to 15 of my specification having the composition (YCa)(MnAl), each exhibiting a small change in electrical resistance to the heat

profile, namely,  $\pm 10^{\circ}$ C over the entire temperature range as shown in Table 7 at page 30 of my specification.

Comparative Example 8 having the composition (SmSr)(MnAl $\underline{Fe}$ ) is directly comparable to inventive Example 16 having the composition (SmSr)(MnAl). As shown in Table 7 at page 30 of my specification, Inventive Example 16 had a very small change in electrical resistance to the heat profile, whereas Comparative Example 3 further containing a small amount of Fe exhibited a large change in electrical resistance to the heat profile exceeding  $\pm 10^{\circ}$ C over the entire temperature range.

Comparative Example 9 having the composition (NdSr)(MnAl**Fe**) is directly comparative to Inventive Example 20 of the specification having the composition (NdSr)(MnAl). As shown in Table 7 at page 30 of my specification, inventive Example 20 exhibited a very small change in electrical resistance to the heat profile, whereas Comparative Example 9 having the same composition but further containing a small amount of Fe exhibited a large change in electrical resistance to the heat profile exceeding ±10°C over the entire temperature range.

Comparative Example 10 having the composition (GdSr)(MnAl $\underline{Fe}$ ) is directly comparative to Inventive Example 21 having the composition (GdSr)(MnAl). As shown in Table 7 at page 30 of my specification, inventive Example 21 exhibited a very small change in electrical resistance to the heat profile, whereas Comparative Example 10 further containing a small amount of Fe exhibited a large change in electrical resistance to the heat profile, namely, in excess of  $\pm 10^{\circ}$ C over the entire temperature range.

Comparative Example 11 shows that the composition  $(NdCa)(MnAl\underline{Fe})$  also exhibits a large change in electrical resistance to the heat profile exceeding  $\pm 10^{\circ}C$  over the entire

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temperature range. Comparative Example 12 likewise shows that <u>addition of Ni in place of</u>

Fe likewise results in a very large change in electrical resistance to the heat profile.

The test data discussed above is summarized in the Table below.

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SiO2       (kΩ)       (kΩ)	-         2113         0.079         1076         0.070         18         30
initial electrical electrical resistance resistance (kΩ) (kΩ)  100°C 900°C 100°C 900°C 1041  1547 0.150 1046 0.141  1980 0.196 1244 0.185  2726 0.064 2649 0.058  2735 0.108 1693 0.102  3489 0.122 1965 0.111	2113 0.079 1076 0.070
initial electrical electrical resistance (kΩ) (kΩ)  100°C 900°C 100°C 1046  1547 0.150 1046  1980 0.196 1244  4148 0.064 2649  2726 0.066 1759  2735 0.108 1693  3489 0.122 1965	2113 0.079 1076
initial electrical resistance (kΩ) 100°C 900°C 1547 0.150 1980 0.196 2726 0.066 2735 0.108 3489 0.122	2113 0.079
100°C (κΩ) 1980 2735 2735 3489	2113
0	1
E I I I I I I	090.0
Fe 0.030 0.086 0.086 0.086	ı
Al 0.865 0.865 0.800 0.800 0.800 0.800 0.800 0.800	0.820
Mn 0.105 0.105 0.114 0.1163 0.163	0.120
2 B I I I I I I	ı
Sr Ca Mg 0.080 0.080 0.080 0.080 0.080 0.080 0.080	1
	0.080
Gd Gd	1
Pigroup 3	1
Sm Nd Sm Nd 0.920 0.920	1
P	0.920
Comparative Examples (YSr)(MnAIFe) (SmSr)(MnAIFe) (GdSr)(MnAIFe) (GdSr)(MnAIFe)	(YSr)(MnAINi)
9 2 8 6 7 1	12

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Change in electrical resistances in terms of temperature (°C)	೨್ಥ006	1	ထု	9	8	3	6-	φ	ဇ	-2	5	က	9	φ
	100°C	7	7	8	10	80	-2	6-	2	5	10	10	10	-
	೨ೢ006	0.059	0.191	0.101	920.0	0.050	0.097	0.068	0.051	0.140	0.107	0.080	0.054	0.186
octrical electrical resistance ance after heating $(k\Omega)$	100°C	3.656	311.0	33.54	31.49	21.80	21.33	18.02	9.268	167.8	97.19	158.3	56.0	1735
	೨,006	0.059	0.186	0.103	0.078	0:050	0.095	0.067	0.051	0.139	0.109	0.081	0.055	0.182
initial electrical resistance (kΩ)	100°C	4.033	303.6	38.77	37.35	25.15	20.63	16.94	9.625	189.7	125.4	212.7	73.05	1703
SiO <sub>2</sub>	SiO <sub>2</sub>		ı	I	1	I	I	I	ı	l	I	ı	ı	I
Z	Ë		ı	I	. 1	I	ı	ı	ı	l	ı	I	I	I
Fe		I	ı	ı	1	I	I	l	1	ı	ı	ı	ı	ı
A		0.820	0.820	0.806	0.794	0.781	908.0	0.794	0.781	0.820	908.0	0.794	0.781	0.820
M	Mn		0.180	0.194	0.206	0.219	0.194	0.206	0.219	0.180	0.194	0.206	0.219	0.180
p 2	Mg	- 0.180	ı	1	1	1	1	1	I	I	1	I	I	I
element of group 2	Ca	0.180	0.180	0.180	0.180	0.180	0.194	0.206	0.219	0.160	0.160	0.160	0.160	090.0
eler	Sr	ı	ı	ı	ı	ı	ı	ı	ı	ı	ı	ı	ı	ı
	рЭ	ı	ı	ı	ı	ı	I	ı	ı	1	I	1	1	I
element of group 3	PΝ	I	ı	ı	ı	ı	ı	ı	1	ı	ı	ı	ı	ı
	Sm	ı	ı	ı	I	ı	I	ı	I	ı	ı	ı	I	I
eleme	<b>\</b>	0.820	0.820	0.820	0.820	0.820	0.806	0.794	0.781	0.840	0.840	0.840	0.840	0.940
Inventive Examples		(YCa)(MnAl)												
		1	2	3	4	5	9	7	∞	တ	9	Ξ	12	13

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Change in electrical resistances in terms of temperature (°C)	೨。006	0	4	-	-3	9	9-	5	8
Change in electrica resistances in terms of temperature (°C)	2,001	2	3	က	5	1	දි-	2	9
electrical resistance after heating (kΩ)	೦್ಲ006	0.082	0.247	0.085	0.197	0.100	0.024	0.086	0.139
	100°C	471.0	1810	203.2	92.32	30.28	6.098	143.0	125.0
	೨。006	0.082	0.251	0.085	0.195	0.101	0.023	0.087	0.143
initial electrical resistance (kΩ)	100°C	512.4	1985	222.9	103.0	31.26	5.474	151.5	142.6
SiO <sub>2</sub>	I	I	1	I	ı	I	I	I	
Z	ı	ı	ı	I	I	ı	I	I	
F. e	I	I	ı	ı	I	ı	ı	I	
₹	0.781	0.820	0.820	0.820	0.855	0.746	0.820	0.820	
M	0.219	0.180	0.180	0.180	0.145	0.254	0.180	0.180	
2 dr	Mg	ı	ı	ı	ı	ı	1	I	I
element of group 2	Ca	0.060	0.060		_	1	l	I	I
eleme	Sr	ı	ŀ	0.180		090'0	0.040	0.180	0.180
	рЭ	1	1	l	ı	I	1	I	0.82
element of group 3	PΝ	_	l	ı	I	ı	ı	0.820	I
	Sm	1	1 1		I	I	I	I	I
<u>ā</u>	λ	0.940	096.0	0.960 0.820	0.940	0.940	0.940	I	I
Inventive Examples		(YCa)(MnAl)	(YCa)(MnAl)	(SmSr)(MnAl)	(Ysr)(MnAi)	(Ysr)(MnAl)	(Ysr)(MnAl)	(NdSr)(MnAl)	(GdSr)(MnAl)
		14	15	16	17	18	19	20	21

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In summary, the test data presented herein demonstrates that the presence of a

transition metal other than Mn and the at least one element selected from elements of Group 3

in the Periodic Table excluding La results in a large change in electrical resistance to the heat

profile, namely, in excess of ±10°C over the entire temperature range. On the other hand, by

excluding any transition metal other Mn and the at least one element selected from Group 3,

in accordance with my invention, there is a small change in electrical resistance to the heat

profile, namely, well within  $\pm 10^{\circ}$ C over the entire temperature range. Tuller et al., which

discloses and allows for incorporation of transition elements other Mn and the at least one

element selected from elements of Group 3 in the Periodic Table, such as Cr, Fe, Co, Ni, Cu,

Ti, Zr and Hf, did not recognize this characteristic feature of my invention.

I declare further that all statements made herein of my own knowledge are true and

that all statements made on information and belief are believed to be true; and further that

these statements were made with the knowledge that willful false statements and the like so

made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the

United States Code, and that such willful false statements may jeopardize the validity of the

application or any patent issuing thereon.

Date: 1/31/2007

Takaaki Chosokabe

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